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# INTEGRATED CIRCUITS, SILICON MONOLITHIC, CMOS 8-INPUT NOR/OR GATE WITH FULLY BUFFERED OUTPUTS

**BASED ON TYPE 4078B** 

ESCC Detail Specification No. 9201/062

Issue 4	August 2014



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DCR No.	CHANGE DESCRIPTION
874	Specification upissued to incorporate editorial changes per DCR.



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#### 1 <u>GENERAL</u>

#### 1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

#### 1.2 <u>APPLICABLE DOCUMENTS</u>

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 9000
- (b) MIL-STD-883, Test Methods and Procedures for Microelectronics

#### 1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

#### 1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

1.4.1 <u>The ESCC Component Number</u> The ESCC Component Number shall be constituted as follows:

Example: 920106201

- Detail Specification Reference: 9201062
- Component Type Variant Number: 01 (as required)

#### 1.4.2 Component Type Variants

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Terminal Material and/or Finish	Weight max g
01	4078B	FP	G2	0.7
02	4078B	FP	G4	0.7
03	4078B	DIP	G2	2.2
04	4078B	DIP	G4	2.2
07	4078B	CCP	2	0.6
08	4078B	SO	G2	0.7
09	4078B	SO	G4	0.7

The terminal material and/or finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.



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#### 1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Units	Remarks
Supply Voltage	$V_{DD}$	-0.5 to 18	V	Note 1
Input Voltage	V <sub>IN</sub>	-0.5 to V <sub>DD</sub> +0.5	V	Note 1 Power on
Input Current	I <sub>IN</sub>	±10	mA	-
Device Power Dissipation (Continuous)	P <sub>D</sub>	200	mW	-
Power Dissipation per Output	P <sub>DSO</sub>	100	mW	-
Operating Temperature Range	$T_{op}$	-55 to +125	°C	T <sub>amb</sub>
Storage Temperature Range	$T_{stg}$	-65 to +150	°C	-
Soldering Temperature For FP, DIP and SO For CCP	T <sub>sol</sub>	+265 +245	°C	Note 2 Note 3

#### NOTES:

- 1. Device is functional for  $3V \le V_{DD} \le 15V$ .
- 2. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same terminal shall not be resoldered until 3 minutes have elapsed.
- 3. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.

#### 1.6 HANDLING PRECAUTIONS

These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

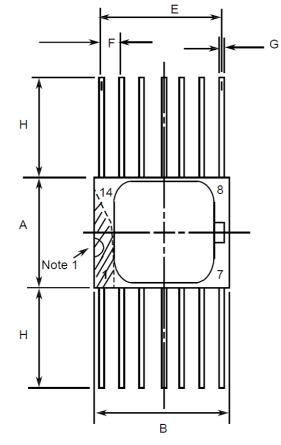
These components are categorised as Class 1 per ESCC Basic Specification No. 23800 with a minimum Critical Path Failure Voltage of 400 Volts.

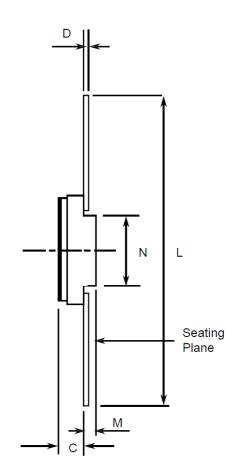
#### 1.7 <u>PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION</u> Consolidated Notes are given following the case drawings and dimensions.



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1.7.1 Flat Package (FP) - 14 Pin





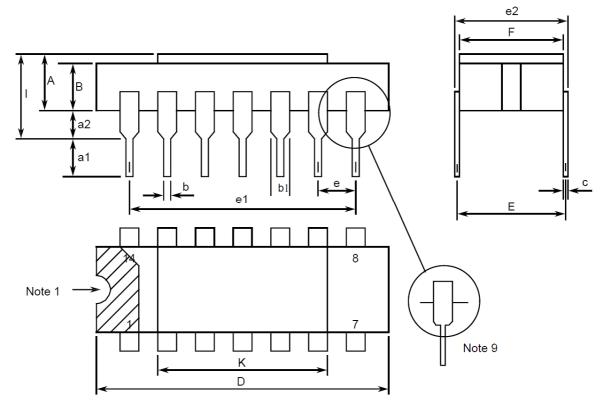
Sympholo	Dimensions mm		Notoo
Symbols	Min	Max	Notes
A	6.75	7.06	
В	9.76	10.14	
С	1.49	1.95	
D	0.1	0.15	5
E	7.5	7.75	
F	1.27	BSC	3, 6
G	0.38	0.48	5
н	6	-	5
L	18.75	22	
М	0.33	0.43	
Ν	4.32 TYPICAL		



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# 1.7.2 <u>Dual-in-line Package (DIP) - 14 Pin</u>



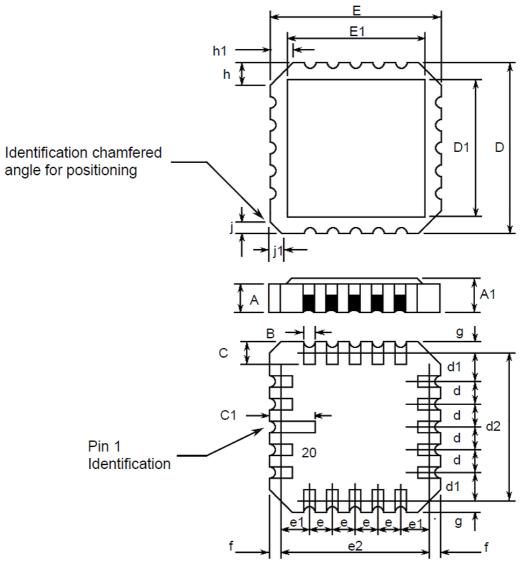
Cumhala	Dimensi	ons mm	Netes
Symbols	Min	Max	Notes
A	2.1	2.54	
a1	3	3.7	
a2	0.63	1.14	2
В	1.82	2.23	
b	0.4	0.5	5
b1	1.27 TYPICAL		5
с	0.2	0.3	5
D	18.79	19.2	
E	7.36	7.87	
е	2.54	BSC	4, 6
e1	15.11	15.37	
e2	7.62	8.12	
F	7.11	7.75	
I	-	3.7	



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Symbols	Dimensi	ions mm	Notes
Symbols	Min	Max	notes
К	10.9	12.1	

## 1.7.3 Chip Carrier Package (CCP) - 20 Terminal



Symbolo	Dimensions mm		Notoo
Symbols	Min	Max	Notes
A	1.14	1.95	
A1	1.63	2.36	
В	0.55	0.72	5
С	1.06	1.47	5

ESCC Detail Specification



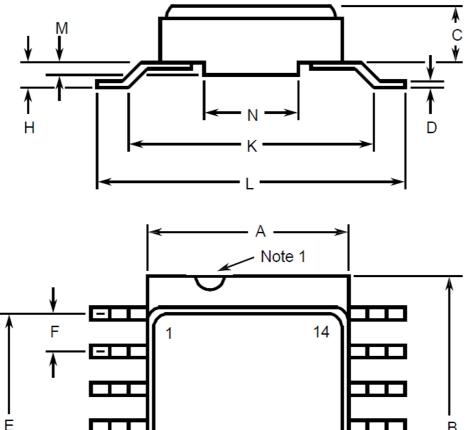
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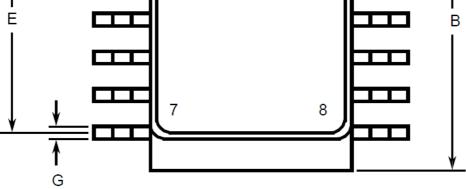
Querra la cile	Dimensions mm		Nistas
Symbols	Min	Max	
C1	1.91	2.41	
D	8.67	9.09	
D1	7.21	7.52	
d, d1	1.27	BSC	3
d2	7.62 BSC		
E	8.67	9.09	
E1	7.21	7.52	
e, e1	1.27	BSC	3
e2	7.62 BSC		
f, g	- 0.76		
h, h1	1.01 TYPICAL		8
j, j1	0.51 TYPICAL		7



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# 1.7.4 Small Outline Ceramic Package (SO) - 14 Pin





Symbolo	Dimensions mm		Notoo
Symbols	Min	Max	Notes
А	6.75	7.06	
В	9.76	10.14	
С	1.49	1.95	
D	0.1	0.15	5
E	7.5	7.75	
F	1.27 BSC		3, 6
G	0.38	0.48	5

**ESCC** Detail Specification



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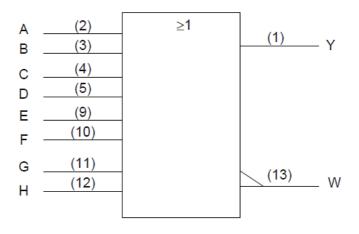
Cum hala	Dimensions mm		Nieteo
Symbols	Min	Max	Notes
Н	0.6	0.9	5
к	9 TYPICAL		
L	10	10.65	
М	0.33	0.43	
N	4.31 TYPICAL		

#### 1.7.5 Notes to Physical Dimensions and Terminal Identification

- 1. Index area; a notch or a dot shall be located adjacent to Pin 1 and shall be within the shaded area shown. For chip carrier packages, the index shall be as shown.
- 2. The dimension shall be measured from the seating plane to the base plane.
- 3. The true position pin spacing is 1.27mm between centrelines. Each pin centreline shall be located within ±0.13mm of its true longitudinal position relative to Pin 1 and the highest pin number.
- 4. The true position pin spacing is 2.54mm between centrelines. Each pin centreline shall be located within ±0.25mm of its true longitudinal position relative to Pin 1 and the highest pin number.
- 5. All terminals.
- 6. 12 spaces.
- 7. Index corner only 2 dimensions.
- 8. 3 non-index corners 6 dimensions.
- 9. For all pins, either pin shape may be supplied.

#### 1.8 <u>FUNCTIONAL DIAGRAM</u>

Pin numbers relate to FP, DIP and SO packages only.





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#### 1.9 <u>PIN ASSIGNMENT</u>

Pin	Funct	ion	Pin	Funct	ion
Pin	FP, DIP and SO	ССР	Pin	FP, DIP and SO	CCP
1	Y Output	-	11	G Input	-
2	A Input	Y Output	12	H Input	-
3	B Input	-	13	W Output	-
4	C Input	A Input	14	V <sub>DD</sub>	E Input
5	D Input	B Input	15	-	F Input
6	-	C Input	16	-	G Input
7	V <sub>SS</sub>	D Input	17	-	H Input
8	-	-	18	-	-
9	E Input	-	19	-	W Output
10	F Input	V <sub>SS</sub>	20	-	V <sub>DD</sub>

## 1.10 TRUTH TABLE

1. Logic Level Definitions: L = Low Level, H = High Level.

2. Positive Logic:

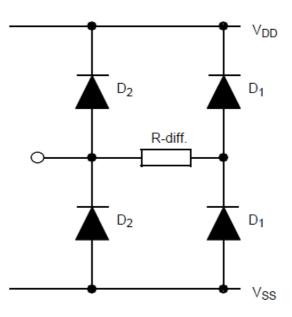
 $W = \overline{A + B + C + D + E + F + G + H}, Y = A + B + C + D + E + F + G + H$ 

INPUTS	OUTPUTS		
A THRU H	W	Y	
All Inputs Low	Н	L	
One or more Inputs High	L	Н	



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#### 1.11 INPUT PROTECTION NETWORK



#### 2 <u>REQUIREMENTS</u>

#### 2.1 <u>GENERAL</u>

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

#### 2.1.1 <u>Deviations from the Generic Specification</u> None.

#### 2.2 <u>MARKING</u>

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) Terminal identification.
- (b) The ESCC qualified components symbol (for ESCC qualified components only).
- (c) The ESCC Component Number.
- (d) Traceability information.



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2.3 <u>ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES</u> Electrical measurements shall be performed at room, high and low temperatures. Consolidated Notes are given after the tables.

## 2.3.1 <u>Room Temperature Electrical Measurements</u> The measurements shall be performed at $T_{amb} = +22 \pm 3$ °C.

Characteristics	Symbols	MIL-STD-883	Test Conditions	Lin	nits	Units
		Test Method	Note 1	Min	Max	
Functional Test 1	-	3014	Verify Truth Table without Load $V_{IL} = 0V, V_{IH} = 3V$ $V_{DD} = 3V, V_{SS} = 0V$ Note 2	-	-	-
Functional Test 2	-	3014	Verify Truth Table without Load $V_{IL} = 0V, V_{IH} = 15V$ $V_{DD} = 15V, V_{SS} = 0V$ Note 2	-	-	-
Quiescent Current	I <sub>DD</sub>	3005	$V_{IL} = 0V, V_{IH} = 15V$ $V_{DD} = 15V, V_{SS} = 0V$ Note 3	-	100	nA
Low Level Input Current	I <sub>IL</sub>	3009	$V_{IN}$ (Under Test) = 0V $V_{DD}$ = 15V, $V_{SS}$ = 0V	-	-50	nA
High Level Input Current	I <sub>IH</sub>	3010	$V_{IN}$ (Under Test) = 15V $V_{DD}$ = 15V, $V_{SS}$ = 0V	-	50	nA
Low Level Output Voltage 1	V <sub>OL1</sub>	3007	$V_{IL} = 0V, V_{IH} = 15V,$ $I_{OL} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	-	50	mV
Low Level Output Voltage 2 (Noise Immunity)	V <sub>OL2</sub>	3007		-	500	mV
Low Level Output Voltage 3 (Noise Immunity)	V <sub>OL3</sub>	3007	$V_{IL} = 4V, V_{IH} = 11V,$ $I_{OL} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	-	1.5	V
High Level Output Voltage 1	V <sub>OH1</sub>	3006	$V_{IL} = 0V, V_{IH} = 15V,$ $I_{OH} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	14.95	-	V
High Level Output Voltage 2 (Noise Immunity)	V <sub>OH2</sub>	3006		4.5	-	V
High Level Output Voltage 3 (Noise Immunity)	V <sub>OH3</sub>	3006	$V_{IL} = 4V, V_{IH} = 11V,$ $I_{OH} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	13.5	-	V



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Characteristics	Symbols	MIL-STD-883	Test Conditions	Limits		Units
		Test Method	Note 1	Min	Max	
Low Level Output Current 1	I <sub>OL1</sub>	-		510	-	μA
Low Level Output Current 2	I <sub>OL2</sub>	-	$V_{IL} = 0V, V_{IH} = 15V, V_{OL} = 1.5V V_{DD} = 15V, V_{SS} = 0V V_{OD} = 4$	3.4	-	mA
High Level Output Current 1	I <sub>OH1</sub>	-	$V_{IL} = 0V, V_{IH} = 5V,$ $V_{OH} = 4.6V$ $V_{DD} = 5V, V_{SS} = 0V$ Note 4	-510	-	μA
High Level Output Current 2	I <sub>OH2</sub>	-	$V_{IL} = 0V, V_{IH} = 15V, V_{OH} = 13.5V V_{DD} = 15V, V_{SS} = 0V V_{OD} = 4$	-3.4	-	mA
Threshold Voltage N-Channel	V <sub>THN</sub>	-	A Input at Ground All Other Inputs: $V_{IN} = 5V$ $V_{DD} = 5V$ , $I_{SS} = -10\mu A$	-0.7	-3	V
Threshold Voltage P-Channel	V <sub>THP</sub>	-	A Input at Ground All Other Inputs: $V_{IN} = -5V$ $V_{SS} = -5V$ , $I_{DD} = 10\mu A$	0.7	3	V
Input Clamp Voltage 1, to V <sub>SS</sub>	V <sub>IC1</sub>	-	I <sub>IN</sub> (Under Test) = -100μΑ V <sub>DD</sub> = Open, V <sub>SS</sub> = 0V All Other Pins Open	-	-2	V
Input Clamp Voltage 2, to V <sub>DD</sub>	V <sub>IC2</sub>	-	$V_{IN}$ (Under Test) = 6V R = 30k $\Omega$ , $V_{SS}$ = Open All Other Pins Open Note 5	3	-	V
Input Capacitance	C <sub>IN</sub>	3012		-	7.5	pF
Propagation Delay Low to High, A to W	t <sub>PLH</sub>	3003		-	250	ns



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Characteristics	Symbols	-	Test Conditions	Limits		Units
		Test Method	Note 1	Min	Max	
Propagation Delay High to Low, A to W	t <sub>PHL</sub>	3003		-	250	ns
Transition Time Low to High, W	t <sub>тLH</sub>	3004		_	150	ns
Transition Time High to Low, W	t <sub>THL</sub>	3004		-	150	ns

## 2.3.2 <u>High and Low Temperatures Electrical Measurements</u> The measurements shall be performed at $T_{amb} = +125 (+0 -5)$ °C and $T_{amb} = -55 (+5 -0)$ °C.

Characteristics	Symbols MIL-STD-883 Test Conditions				nits	Units
		Test Method	Note 1	Min	Max	
Functional Test 1	-	3014	Verify Truth Table without Load $V_{IL} = 0V, V_{IH} = 3V$ $V_{DD} = 3V, V_{SS} = 0V$ Note 2	-	-	-
Functional Test 2	-	3014	Verify Truth Table without Load $V_{IL} = 0V, V_{IH} = 15V$ $V_{DD} = 15V, V_{SS} = 0V$ Note 2	-	-	-
Quiescent Current	I <sub>DD</sub>	3005	$V_{IL} = 0V, V_{IH} = 15V$ $V_{DD} = 15V, V_{SS} = 0V$ Note 3 $T_{amb} = +125 \text{ °C}$ $T_{amb} = -55 \text{ °C}$	-	1 0.1	μA



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Symbols	MIL-STD-883	Test Conditions	Limits		Units
	Test Method	Note 1	Min	Max	
IIL	3009	$V_{IN} \text{ (Under Test)} = 0V$ $V_{DD} = 15V, V_{SS} = 0V$ $T_{amb} = +125 \text{ °C}$ $T_{amb} = -55 \text{ °C}$	- -	-100 -50	nA
Ι <sub>ιΗ</sub>	3010	$V_{IN} \text{ (Under Test)} = 15V$ $V_{DD} = 15V, V_{SS} = 0V$ $T_{amb} = +125 \text{ °C}$ $T_{amb} = -55 \text{ °C}$	-	100 50	nA
V <sub>OL1</sub>	3007	$V_{IL} = 0V, V_{IH} = 15V,$ $I_{OL} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	-	50	mV
V <sub>OL2</sub>	3007		-	500	mV
V <sub>OL3</sub>	3007	$V_{IL} = 4V, V_{IH} = 11V,$ $I_{OL} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	-	1.5	V
V <sub>OH1</sub>	3006	$V_{IL} = 0V, V_{IH} = 15V,$ $I_{OH} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	14.95	-	V
V <sub>OH2</sub>	3006		4.5	-	V
V <sub>OH3</sub>	3006	$V_{IL} = 4V, V_{IH} = 11V,$ $I_{OH} = 0A$ $V_{DD} = 15V, V_{SS} = 0V$	13.5	-	V
I <sub>OL1</sub>	-	$V_{IL} = 0V, V_{IH} = 5V, V_{OL} = 0.4V V_{DD} = 5V, V_{SS} = 0V V_{DD} = 5V, V_{SS} = 0V V_{Note 4} T_{amb} = +125 \ ^{\circ}C T_{amb} = -55 \ ^{\circ}C$	360 640		μA
I <sub>OL2</sub>	-	$V_{IL} = 0V, V_{IH} = 15V, V_{OL} = 1.5V V_{DD} = 15V, V_{SS} = 0V V_{DD} = 15V, V_{SS} = 0V V_{OD} = 4 T_{amb} = +125 \ ^{o}C$	2.4	-	mA
	I <sub>IH</sub> V <sub>OL1</sub> V <sub>OL2</sub> V <sub>OL3</sub> V <sub>OH1</sub> V <sub>OH2</sub> V <sub>OH3</sub> I <sub>OL1</sub>	I <sub>IH</sub> 3010   V <sub>OL1</sub> 3007   V <sub>OL2</sub> 3007   V <sub>OL3</sub> 3007   V <sub>OL1</sub> 3006   V <sub>OH2</sub> 3006   V <sub>OH3</sub> 3006   I <sub>OL1</sub> -	III   3009   VIN (Under Test) = 0V VDD = 15V, VSS = 0V Tamb = +125 °C Tamb = +55 °C     IIH   3010   VIN (Under Test) = 15V VDD = 15V, VSS = 0V Tamb = +125 °C Tamb = +125 °C     VOL1   3007   VIL = 0V, VIH = 15V, IOL = 0A VDD = 15V, VSS = 0V     VOL2   3007   VIL = 1.5V, VIH = 3.5V, IOL = 0A VDD = 5V, VSS = 0V     VOL3   3007   VIL = 4V, VIH = 11V, IOL = 0A VDD = 5V, VSS = 0V     VOH3   3006   VIL = 0V, VIH = 15V, IOH = 0A VDD = 15V, VSS = 0V     VOH3   3006   VIL = 1.5V, VIH = 3.5V, IOH = 0A VDD = 5V, VSS = 0V     VOH3   3006   VIL = 4V, VIH = 11V, IOH = 0A VDD = 5V, VSS = 0V     VOH3   3006   VIL = 4V, VIH = 11V, IOH = 0A VDD = 5V, VSS = 0V     IOL1   -   VIL = 0V, VIH = 5V, VOI = 0.4V VDD = 15V, VSS = 0V     IOL2   -   VIL = 0V, VIH = 15V, VOI = 1.5V VOI = 1.5V, VSS = 0V	$\begin{tabular}{ c c c c c } \hline Min & Min \\ \hline H_{L} & 3009 & V_{IN} (Under Test) = 0V \\ V_{DD} = 15V, V_{SS} = 0V \\ T_{amb} = +125 \ ^{\circ}C & - \\ \hline T_{amb} = -55 \ ^{\circ}C & - \\ \hline \end{bmatrix} \\ \hline H_{H} & 3010 & V_{IN} (Under Test) = 15V \\ V_{DD} = 15V, V_{SS} = 0V \\ \hline T_{amb} = +125 \ ^{\circ}C & - \\ \hline T_{amb} = -55 \ ^{\circ}C & - \\ \hline \end{bmatrix} \\ \hline V_{OL1} & 3007 & V_{IL} = 0V, V_{IH} = 15V, \\ I_{OL} = 0A \\ V_{DD} = 15V, V_{SS} = 0V \\ \hline \end{bmatrix} \\ \hline V_{OL2} & 3007 & V_{IL} = 1.5V, V_{IH} = 3.5V, \\ I_{OL} = 0A \\ V_{DD} = 5V, V_{SS} = 0V \\ \hline \end{bmatrix} \\ \hline \\ \hline V_{OL3} & 3007 & V_{IL} = 4V, V_{IH} = 11V, \\ I_{OL} = 0A \\ V_{DD} = 5V, V_{SS} = 0V \\ \hline \\ \hline \\ \hline \\ V_{OH1} & 3006 & V_{IL} = 0V, V_{IH} = 15V, \\ I_{OH} = 0A \\ V_{DD} = 15V, V_{SS} = 0V \\ \hline \\ \hline \\ \hline \\ V_{OH2} & 3006 & V_{IL} = 1.5V, V_{IH} = 3.5V, \\ I_{OH} = 0A \\ V_{DD} = 5V, V_{SS} = 0V \\ \hline \\ \hline \\ \hline \\ \hline \\ V_{OH3} & 3006 & V_{IL} = 4V, V_{IH} = 11V, \\ I_{OH} = 0A \\ V_{DD} = 5V, V_{SS} = 0V \\ \hline \\ \hline \\ \hline \\ \hline \\ V_{OH3} & 3006 & V_{IL} = 4V, V_{IH} = 11V, \\ I_{OH} = 0A \\ V_{DD} = 5V, V_{SS} = 0V \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ I_{OL1} & - & V_{IL} = 0V, V_{IH} = 5V, \\ V_{OL} = 0.4V \\ V_{DD} = 5V, V_{SS} = 0V \\ \hline \\ \hline \\ \hline \\ \hline \\ \hline \\ I_{OL2} & - & V_{IL} = 0V, V_{IH} = 15V, \\ V_{OL} = 1.5V, V_{SS} = 0V \\ \hline \\ $	$\begin{tabular}{ c c c c c c c } \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & Min & Max \\ \hline Min & Max & -100 \\ \hline T_{amb} = +125 ^{\circ}C & - & - & -100 \\ \hline I_{H} & 3001 & V_{IL} = 0V, V_{IH} = 15V, & - & 100 \\ \hline T_{amb} = +55 ^{\circ}C & - & 50 \\ \hline V_{OL1} & 3007 & V_{IL} = 0V, V_{IH} = 15V, & - & 500 \\ \hline V_{OL2} & 3007 & V_{IL} = 4V, V_{IH} = 11V, & - & 1.5 \\ \hline V_{OL3} & 3007 & V_{IL} = 4V, V_{IH} = 11V, & - & 1.5 \\ \hline V_{OH1} & 3006 & V_{IL} = 0V, V_{IH} = 3.5V, & 4.5 & - & \\ \hline V_{OH2} & 3006 & V_{IL} = 1.5V, V_{SS} = 0V \\ \hline V_{OH3} & 3006 & V_{IL} = 4V, V_{IH} = 11V, & 13.5 & - & \\ \hline V_{OH3} & 3006 & V_{IL} = 0V, V_{IH} = 5V, & \\ \hline V_{OL} = 0A, & V_{DD} = 5V, V_{SS} = 0V \\ \hline I_{OL1} & - & V_{IL} = 0V, V_{IH} = 5V, & \\ \hline V_{OL} = 0A, & V_{DD} = 5V, V_{SS} = 0V \\ \hline I_{OL2} & - & V_{IL} = 0V, V_{IH} = 15V, & \\ \hline V_{OL2} = 1.5V, V_{SS} = 0V & \\ \hline Mox e 4 & \\ \hline T_{amb} = +125 ^{\circ}C & 360 & - & \\ \hline I_{OL2} & - & V_{IL} = 0V, V_{IH} = 15V, & \\ \hline V_{OL} = 1.5V, V_{SS} = 0V & \\ \hline Note 4 & \\ \hline T_{amb} = +125 ^{\circ}C & 2.4 & - & \\ \hline \end{bmatrix}$



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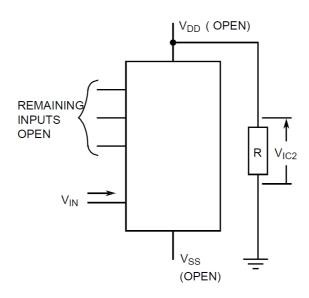
Characteristics	Symbols		Test Conditions	Limits		Units
		Test Method	Note 1	Min	Max	
High Level Output Current 1	I <sub>OH1</sub>	-	$V_{IL} = 0V, V_{IH} = 5V,$ $V_{OH} = 4.6V$ $V_{DD} = 5V, V_{SS} = 0V$ Note 4 $T_{amb} = +125 \text{ °C}$ $T_{amb} = -55 \text{ °C}$	-360 -640		μA
High Level Output Current 2	I <sub>OH2</sub>	-	$V_{IL} = 0V, V_{IH} = 15V, V_{OH} = 13.5V V_{DD} = 15V, V_{SS} = 0V V_{OD} = 15V, V_{SS} = 0V V_{OD} = +125 \ ^{\circ}C T_{amb} = +125 \ ^{\circ}C$	-2.4 -4.2	-	mA
Threshold Voltage N-Channel	V <sub>THN</sub>	-	A Input at Ground All Other Inputs: $V_{IN} = 5V$ $V_{DD} = 5V$ , $I_{SS} = -10\mu A$ $T_{amb} = +125$ °C $T_{amb} = -55$ °C	-0.3 -0.7	-3.5 -3.5	V
Threshold Voltage P-Channel	V <sub>THP</sub>	-	A Input at Ground All Other Inputs: $V_{IN} = -5V$ $V_{SS} = -5V$ , $I_{DD} = 10\mu A$ $T_{amb} = +125$ °C $T_{amb} = -55$ °C	0.3 0.7	3.5 3.5	V

#### 2.3.3 Notes to Electrical Measurement Tables

- 1. Unless otherwise specified all inputs and outputs shall be tested for each characteristic, inputs not under test shall be  $V_{IN} = V_{SS}$  or  $V_{DD}$  and outputs not under test shall be open.
- 2. Functional tests shall be performed to verify Truth Table with  $V_{OH} \ge V_{DD}$ -0.5V,  $V_{OL} \le 0.5V$ . The maximum time to output comparator strobe = 300µs.
- 3. Quiescent Current shall be tested using the following input conditions:
  - (a) All inputs =  $V_{IH}$ 
    - (b) All inputs =  $V_{IL}$
- 4. Interchange of forcing and measuring parameters is permitted.
- 5. Input Clamp Voltage 2 to V<sub>DD</sub>, V<sub>IC2</sub>, shall be tested on each input as follows:



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- 6. Guaranteed but not tested.
- 7. Read and record measurements shall be performed on a sample of 32 components with 0 failures permitted.

The pulse generator shall have the following characteristics:

$$\label{eq:V_GEN} \begin{split} &V_{\text{GEN}} = 0 \text{ to } V_{\text{DD}} \text{; } f_{\text{GEN}} = 500 \text{kHz} \text{; } t_r \text{ and } t_f \leq 15 \text{ns} \text{ (10\% to 90\%)} \text{; } \text{duty cycle} = 50\% \text{; } Z_{\text{out}} = 50\Omega \text{.} \\ &\text{Output load capacitance } C_L = 50 \text{pF} \pm 5\% \text{ including scope probe, wiring and stray capacitance} \\ &\text{without component in the test fixture. Output load resistance } R_L = 200 \text{k}\Omega \pm 5\% \text{.} \end{split}$$

Propagation delay shall be measured referenced to the 50% input and output voltages. Transition time shall be measured referenced to the 10% and 90% output voltage.

#### 2.4 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$  = +22 ±3 °C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols		Limits	Units	
		Drift	Abso	olute	
		Value Δ	Min	Max	
Quiescent Current	I <sub>DD</sub>	±50	-	100	nA
Low Level Output Current 1	I <sub>OL1</sub>	±15% (2)	510	-	μA
High Level Output Current 1	I <sub>OH1</sub>	±15% (2)	-510	-	μA
Threshold Voltage N-Channel	V <sub>THN</sub>	±0.3	-0.7	-3	V
Threshold Voltage P-Channel	V <sub>THP</sub>	±0.3	0.7	3	V



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#### NOTES:

- 1. Unless otherwise specified all inputs and outputs shall be tested for each characteristic.
- 2. Percentage of limit value if voltage is the measuring parameter.

#### 2.5 INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$  = +22 ±3 °C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic where specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift	Abs	olute	
		Value Δ	Min	Max	
Functional Test 1	-	-	-	-	-
Quiescent Current	I <sub>DD</sub>	±50	-	100	nA
Low Level Input Current	I <sub>IL</sub>	-	-	-50	nA
High Level Input Current	I <sub>IH</sub>	-	-	50	nA
Low Level Output Voltage 1	V <sub>OL1</sub>	-	-	50	mV
Low Level Output Voltage 2 (Noise Immunity)	V <sub>OL2</sub>	-	-	500	mV
High Level Output Voltage 1	V <sub>OH1</sub>	-	14.95	-	V
High Level Output Voltage 2 (Noise Immunity)	V <sub>OH2</sub>	-	4.5	-	V
Low Level Output Current 1	I <sub>OL1</sub>	±15% (3)	510	-	μA
Low Level Output Current 2	I <sub>OL2</sub>	±15% (3)	3.4	-	mA
High Level Output Current 1	I <sub>OH1</sub>	±15% (3)	-510	-	μA
High Level Output Current 2	I <sub>OH2</sub>	±15% (3)	-3.4	-	mA
Threshold Voltage N-Channel	V <sub>THN</sub>	±0.3	-0.7	-3	V
Threshold Voltage P-Channel	V <sub>THP</sub>	±0.3	0.7	3	V

#### NOTES:

1. Unless otherwise specified all inputs and outputs shall be tested for each characteristic.

- 2. The drift values ( $\Delta$ ) are applicable to the Operating Life test only.
- 3. Percentage of limit value if voltage is the measuring parameter.



#### 2.6 HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS

#### 2.6.1 <u>N-Channel HTRB</u>

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T <sub>amb</sub>	+125 (+0 -5)	°C
Outputs Y, W	V <sub>OUT</sub>	Open	V
Inputs A, B, C, D	V <sub>IN</sub>	V <sub>SS</sub>	V
Inputs E, F, G, H	V <sub>IN</sub>	V <sub>DD</sub>	V
Positive Supply Voltage	V <sub>DD</sub>	15 (+0 -0.5)	V
Negative Supply Voltage	V <sub>SS</sub>	0	V
Duration	t	72	Hours

## NOTES:

1. Input Protection Resistor =  $2k\Omega$  min to  $47k\Omega$  max.

#### 2.6.2 <u>P-Channel HTRB</u>

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T <sub>amb</sub>	+125 (+0 -5)	°C
Outputs Y, W	V <sub>OUT</sub>	Open	V
Inputs A, B, C, D	V <sub>IN</sub>	V <sub>DD</sub>	V
Inputs E, F, G, H	V <sub>IN</sub>	V <sub>SS</sub>	V
Positive Supply Voltage	V <sub>DD</sub>	15 (+0 -0.5)	V
Negative Supply Voltage	V <sub>SS</sub>	0	V
Duration	t	72	Hours

#### NOTES:

1. Input Protection Resistor =  $2k\Omega$  min to  $47k\Omega$  max.



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## 2.7 POWER BURN-IN CONDITIONS

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T <sub>amb</sub>	+125 (+0 -5)	°C
Outputs Y, W	V <sub>OUT</sub>	V <sub>DD</sub> /2	V
Inputs B, D, E, G	V <sub>IN</sub>	V <sub>GEN1</sub>	V
Inputs A, C, F, H	V <sub>IN</sub>	V <sub>GEN2</sub>	V
Pulse Voltage	$V_{\text{GEN}}$	0V to $V_{\text{DD}}$	V
Pulse Frequency Square Wave	f <sub>gen1</sub> f <sub>gen2</sub>	50k 25k 50% Duty Cycle	Hz
Positive Supply Voltage	V <sub>DD</sub>	15 (+0 -0.5)	V
Negative Supply Voltage	V <sub>SS</sub>	0	V

## NOTES:

1. Input Protection Resistor = Output Load =  $2k\Omega$  min to  $47k\Omega$  max.

## 2.8 OPERATING LIFE CONDITIONS

The conditions shall be as specified for Power Burn-in.



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# APPENDIX 'A'

#### AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS	
Deviations from Screening Tests - Chart F3	External Visual Inspection: The criteria applicable to chip-outs are those described in MIL-STD-883, Test Method 2009, Paras 3.3.6(b) and 3.3.7(a).	
	High Temperature Reverse Bias Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.	
	Power Burn-in test is performed using STMicroelectronics Specification Ref: 0019255.	
	Solderability is not applicable unless specifically stipulated in the Purchase Order.	
Deviations from Qualification and Periodic Tests - Chart F4	External Visual Inspection: The criteria applicable to chip-outs are those described in MIL-STD-883, Test Method 2009, Paras 3.3.6(b) and 3.3.7(a).	
	Operating Life: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.	
Deviations from High and Low Temperatures Electrical Measurements	High and Low Temperatures Electrical Measurements may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes High and Low Temperatures Electrical Measurements per the Detail Specification.	
	A summary of the pilot lot testing shall be provided if required by the Purchase Order.	
Deviations from Room Temperature Electrical Measurements	All AC characteristics (Capacitance and Timings) may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes AC characteristic measurements per the Detail Specification.	
	A summary of the pilot lot testing shall be provided if required by the Purchase Order.	